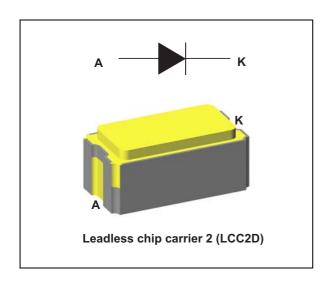


Aerospace 0.3 A - 75 V switching diode

Datasheet - production data



Description

Packaged in LCC2D this device intended for use in low voltage, high frequency inverters, free wheeling, polarity protection and other aerospace applications.

Features

- · Surface mount hermetic package
- High thermal conductivity materials
- Very small conduction losses
- · Negligible switching losses
- Extremely fast switching
- Low forward voltage drop
- Target radiation qualification
 - 150 krad (Si) low dose rate
 - 3 Mrad (Si) high dose rate
- Package mass: 0.12 g

Table 1. Device summary⁽¹⁾

| Order code | ESCC detailed specification | Quality level | Lead finish | EPPL | I _{F(AV)} | V _{RRM} | T _{j(max)} | VF _(max) |
|------------|-----------------------------------|-------------------|----------------|--------|--------------------|------------------|---------------------|---------------------|
| 1N6640UD1 | | Engineering model | Gold | | | | | |
| 1N6640U01D | 5101/027/07 | ESCC | Gold | Target | 0.3 | 75 | 175 | 1,06 |
| 1N6640U02D | 5101/027/08 | ESCC | Solder dip | | | | | |

^{1.} Contact ST sales office for information about the specific conditions for products in die form.

Characteristics 1N6640U

1 Characteristics

Table 2. Absolute ratings (limiting values)

| Symbol | Parameter | | Value | Unit |
|---------------------|--|-------------|-------|------|
| V_{RRM} | Repetitive peak reverse voltage | | 75 | V |
| I _{F(RMS)} | Forward rms current | | 0.5 | Α |
| I _{F(AV)} | Average forward rectified current (1) | 300 | mA | |
| I _{FSM} | Forward surge current $t_{p} = 8.3 \text{ ms sinusoidal}, \\ t_{amb} \leq 25 \text{ °C}$ | | 2 | А |
| T _{stg} | Storage temperature range | -65 to +175 | °C | |
| T _j | Operating junction temperature range | -65 to +175 | °C | |
| T _{sol} | Maximum soldering temperature (2) | | 245 | °C |

^{1.} For all variants at $T_c \geq$ +155 °C per diode, derate linearly to 0 A at +175 °C.

Table 3. Thermal resistance

| Symbol | Parameter | Value | Unit |
|-----------------------|----------------------|-------|------|
| R _{th (j-c)} | Junction to case (1) | 60 | °C/W |
| R _{th (j-a)} | Junction to ambient | 280 | C/VV |

^{1.} Package mounted on infinite heatsink

Table 4. Static electrical characteristics

| Symbol | Parameter | Tests conditions | | Min. | Тур. | Max. | Unit |
|--------------------------------|-------------------|-------------------------|-------------------------|------|------|------|------|
| V _{BR} ⁽¹⁾ | Breakdown voltage | T _j = 25 °C | I _R = 10 μA | 75 | - | - | V |
| I _R ⁽¹⁾ | Reverse current | T _j = 25 °C | V _R = 50 V | - | - | 40 | nA |
| Reverse current | Neverse current | T _j = 150 °C | = 150 °C | - | - | 30 | μA |
| | Forward voltage | T _j = 25 °C | I _F = 1 mA | 540 | - | 630 | |
| | | T _j = 25 °C | I _F = 50 mA | 760 | - | 890 | |
| V _F ⁽²⁾ | | T _j = 25 °C | I _F = 100 mA | 820 | - | 980 | mV |
| | | T _j = 25 °C | I _F = 200 mA | 870 | - | 1100 | |
| | | T _j = -55 °C | I _F = 200 mA | - | - | 1200 | |

^{1.} Pulse test: $tp = 10 \text{ ms}, \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.74 \times I_{F(AV)} + 1.00 \times I_{F}^{2}(RMS)$$

^{2.} Maximum duration 5 s. The same package must not be re-soldered until 3 minutes have elapsed.

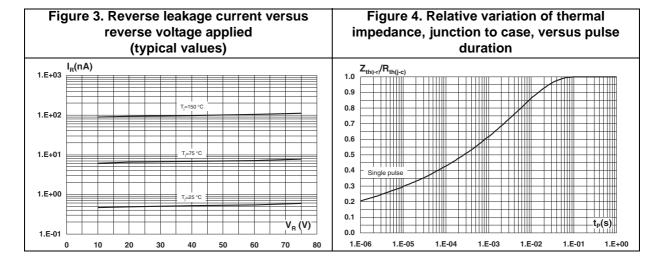
^{2.} Pulse test: $tp = 680 \mu s$, $\delta < 2\%$

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Table 5. Dynamic characteristics

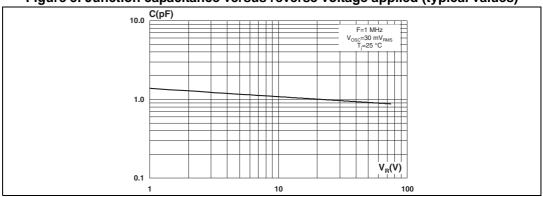
| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|---------------------|--------------------------|--|------|------|------|------|
| t _{rr} Rev | Reverse recovery time | $I_F = I_R = 10 \text{ mA}$ | - | - | 9 | ns |
| | Theverse recovery time | $I_F = 1 \text{ A}, V_r = 30 \text{ V}, dI/dt = -15 \text{ A/}\mu\text{s}$ | | | 20 | 113 |
| V _{FP} | Forward recovery voltage | I _{FM} = 200 mA | - | - | 5 | ٧ |
| t _{FR} | Forward recovery time | I _{FM} = 200 mA | - | - | 20 | ns |
| C _j | Diode capacitance | V _R = 0 V, V = 50 mV, F = 1 MHz | - | - | 3 | pF |

Figure 1. Forward voltage drop versus forward Figure 2. Forward voltage drop versus forward current (typical values) current (maximum values) I_{FM} (A) I_{FM} (A) 1.2 1.0 1.0 0.8 0.6 0.4 0.2 0.2 0.0 0.0 0.2 1.2 1.4 0.0 1.0 1.8 1.8



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Figure 5. Junction capacitance versus reverse voltage applied (typical values)



1N6640U Package information

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

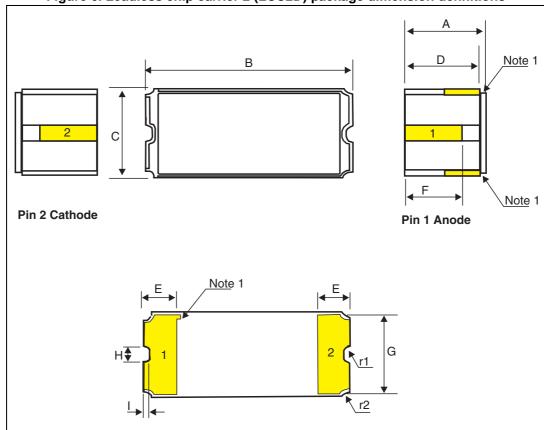


Figure 6. Leadless chip carrier 2 (LCC2D) package dimension definitions

 $1. \quad \text{The anode is identified by metalization in two top internal angles and the index mark}.$

Package information 1N6640U

Table 6. Leadless chip carrier 2 (LCC2D) package dimension values

| | Dimensions | | | | | | |
|------------------|------------|-------------|------|-------|-------|-------|--|
| Ref. | | Millimeters | | | | | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. | |
| A ⁽¹⁾ | 1.86 | 2.03 | 2.20 | 0.073 | 0.080 | 0.087 | |
| В | 4.44 | 4.57 | 4.77 | 0.175 | 0.180 | 0.188 | |
| С | 1.84 | 1.97 | 2.10 | 0.072 | 0.078 | 0.083 | |
| D | 1.53 | 1.70 | 1.87 | 0.060 | 0.067 | 0.074 | |
| Е | 0.48 | - | 0.71 | 0.019 | - | 0.028 | |
| F | - | 1.3 | - | - | 0.051 | - | |
| G | - | 1.67 | - | - | 0.066 | - | |
| Н | - | 0.37 | - | - | 0.015 | - | |
| I | - | 0.15 | - | - | 0.006 | - | |
| r1 | - | 0.15 | - | - | 0.006 | - | |
| r2 | - | 0.20 | - | - | 0.008 | - | |

^{1.} Measurement prior to solder coating the mounting pads on bottom of package

1N6640U Ordering information

3 Ordering information

Table 7. Ordering information⁽¹⁾

| Order code | ESCC detailed specification | Package | Lead finish | Marking ⁽²⁾ | EPPL | Mass | Packing |
|------------|-----------------------------|---------|-------------|------------------------|--------|--------|-------------|
| 1N6640UD1 | - | | Gold | 6640 | - | | |
| 1N6640U01D | 5101/027/07 | LCC2D | Gold | 510102707 | Target | 0.12 g | Waffle pack |
| 1N6640U02D | 5101/027/08 | | Solder dip | 510102708 | - | | |

^{1.} Contact ST sales office for information about the specific conditions for products in die form.

For the engineering models: ST logo, date code, country of origin (FR).

For ESCC flight parts: ST logo, date code, country of origin (FR), ESA logo, serial number of the part within the assembly lot.

4 Other information

4.1 Date code

Date code is structured as describe below:

- EM xyywwz
- ESCC flight yywwz

Where:

- x (EM only): 3, assembly location Rennes (France)
- yy: last two digits year
- ww: week digits
- z: lot index in the week

4.2 Documentation

In *Table 8* is a summary of the documentation provided with each type of products.

Table 8. Documentation provided with each type of products

| Quality level | Documentation |
|-------------------|----------------------------|
| Engineering model | |
| ESCC flight | Certificate of conformance |

^{2.} Specific marking only. The full marking includes in addition:

Revision history 1N6640U

5 Revision history

Table 9. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 26-Mar-2010 | 1 | First issue. |
| 23-Sep-2011 | 2 | Updated order codes in <i>Table 1 Table 7</i> . |
| 8-Nov-2013 | 3 | Updated <i>Table 1</i> , <i>Table 5</i> and <i>Table 7</i> and inserted <i>Other information</i> . |

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